

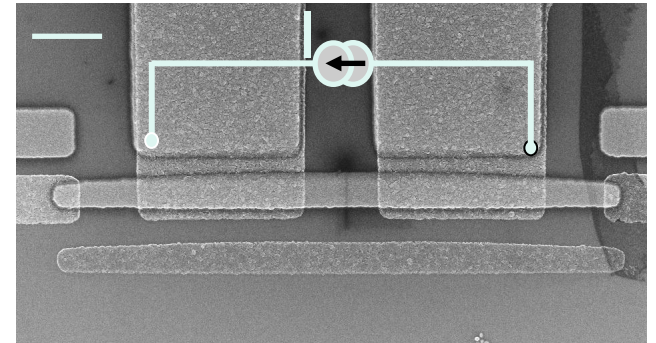
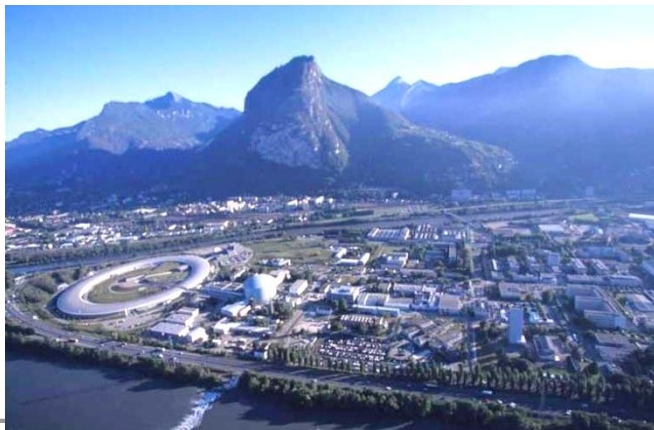
Circuit approach to photonic heat transport applied to superconducting hybrid devices

L. Pascal, S. Rajauria, C. Winkelmann, B. Pannetier, H. Courtois

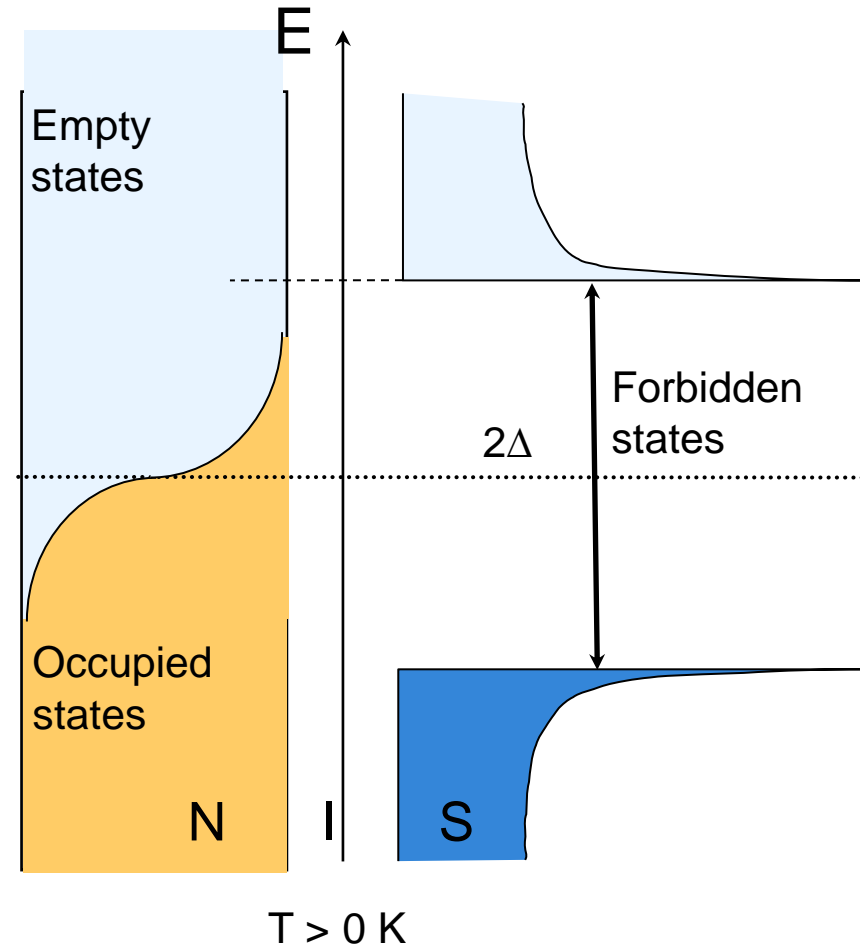
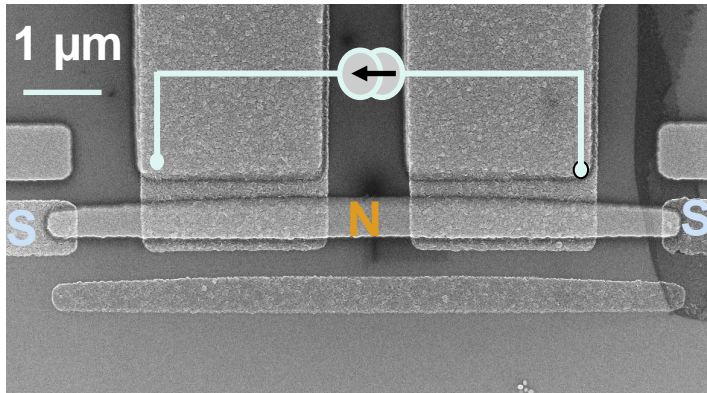
Institut Néel, CNRS, UJF and Grenoble INP

F. Hekking

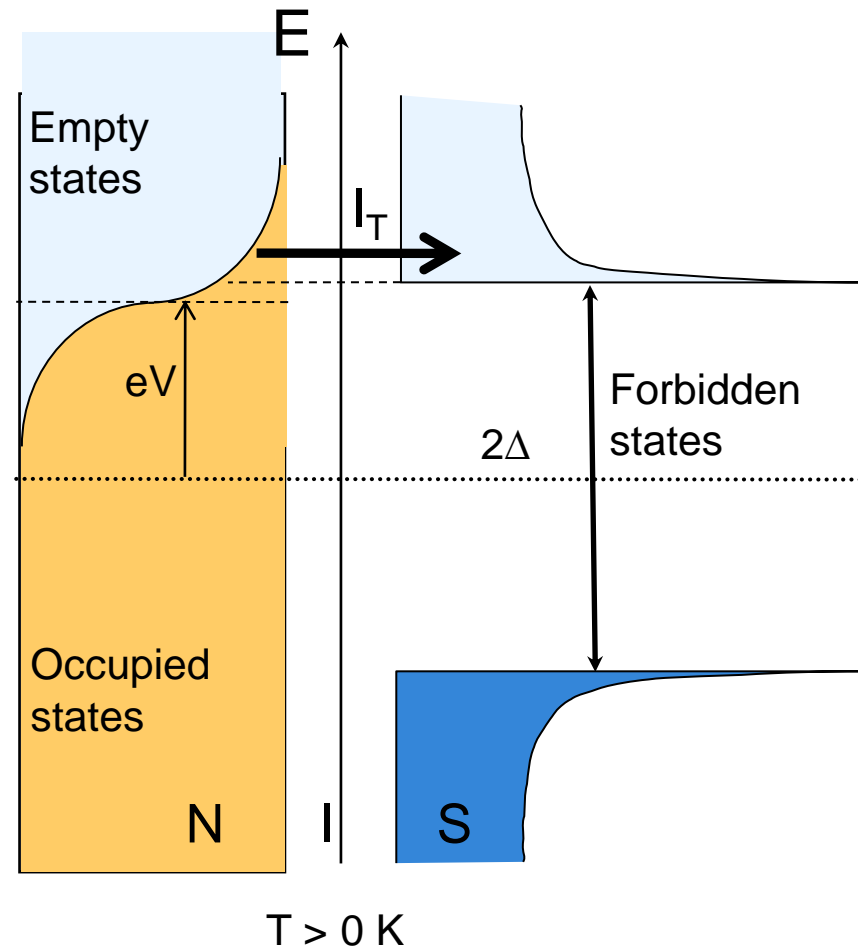
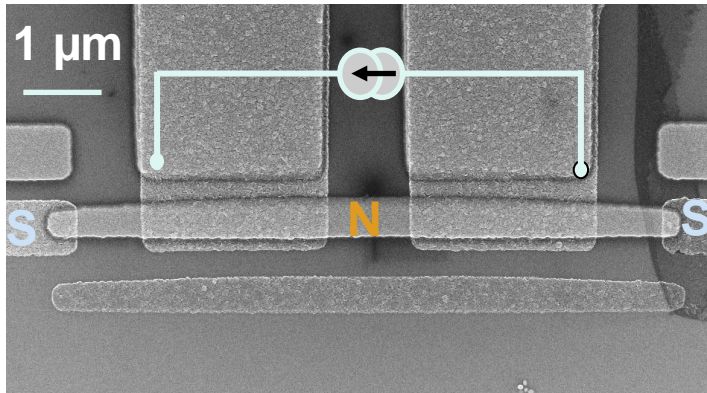
LPMMC, UJF and CNRS



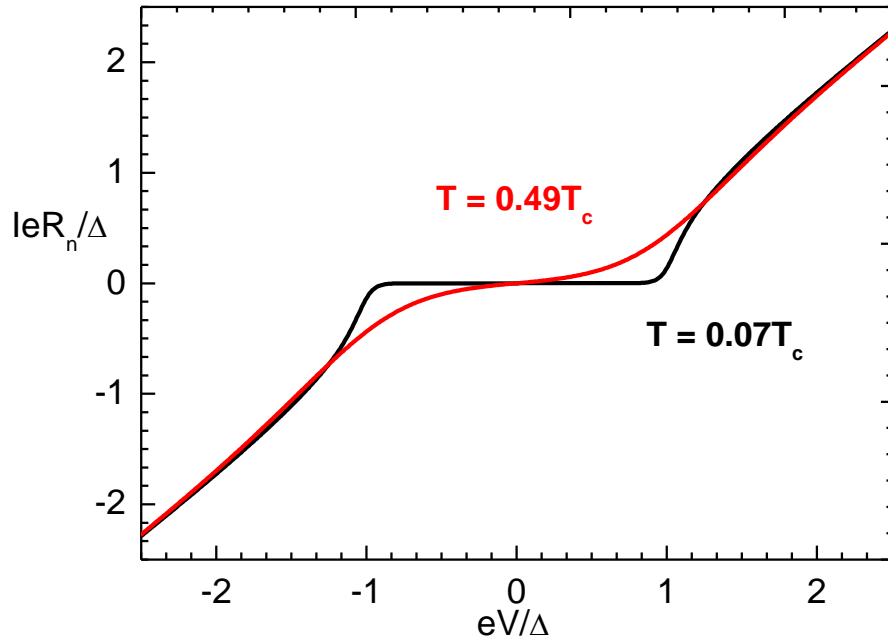
S-I-N-I-S thermometry



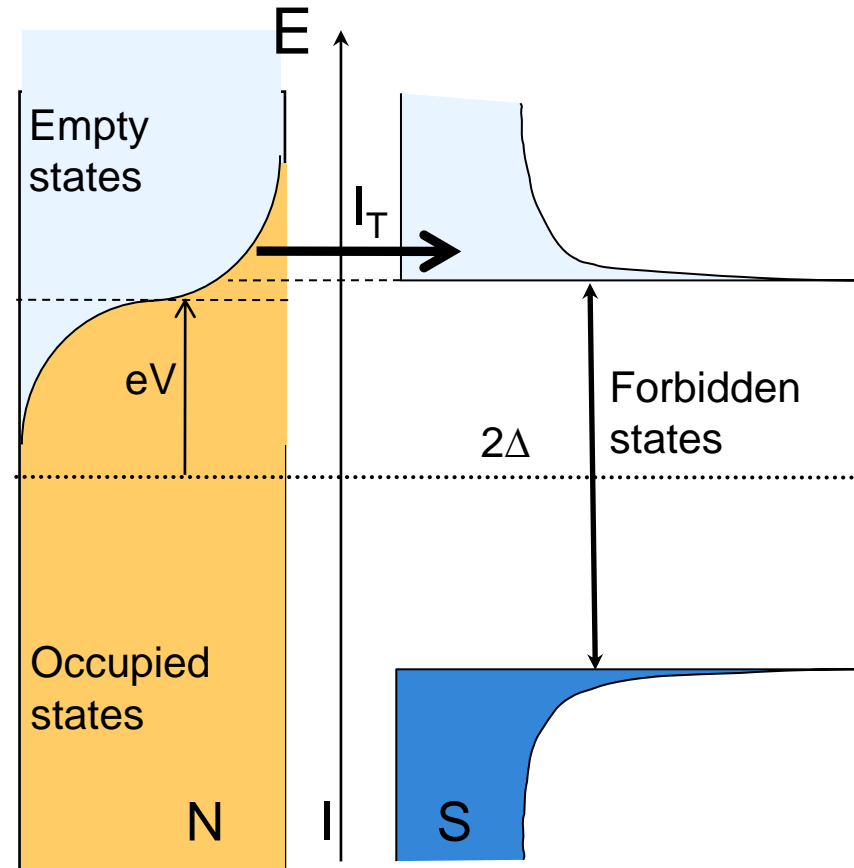
S-I-N-I-S thermometry



S-I-N-I-S thermometry



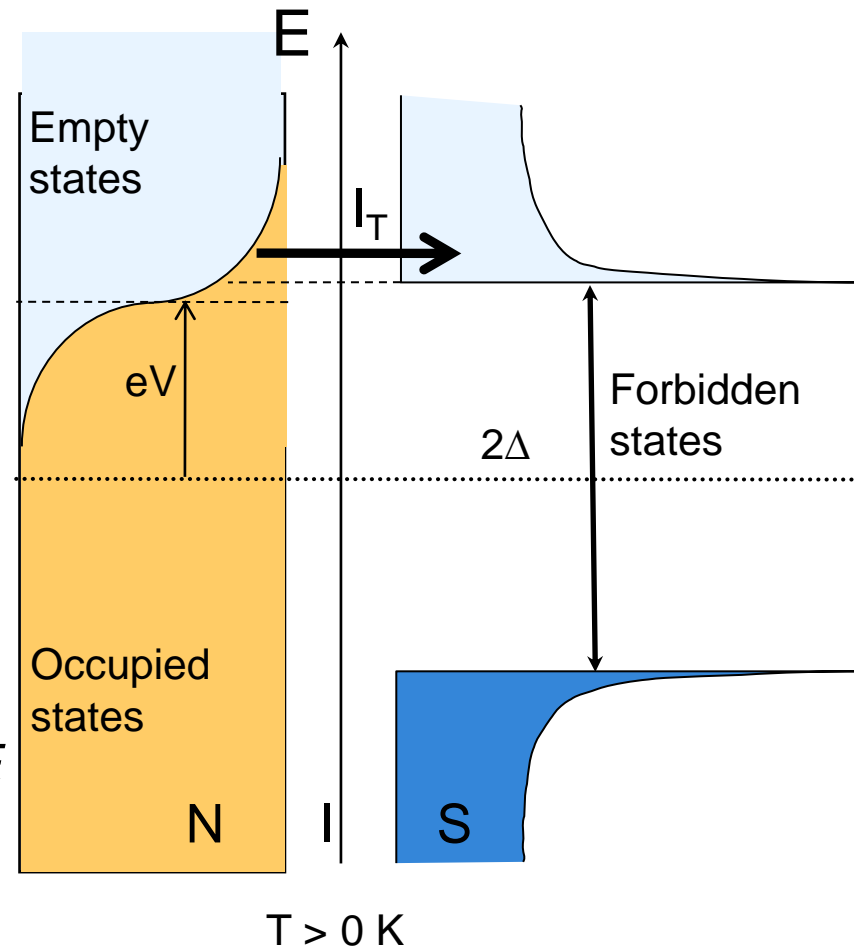
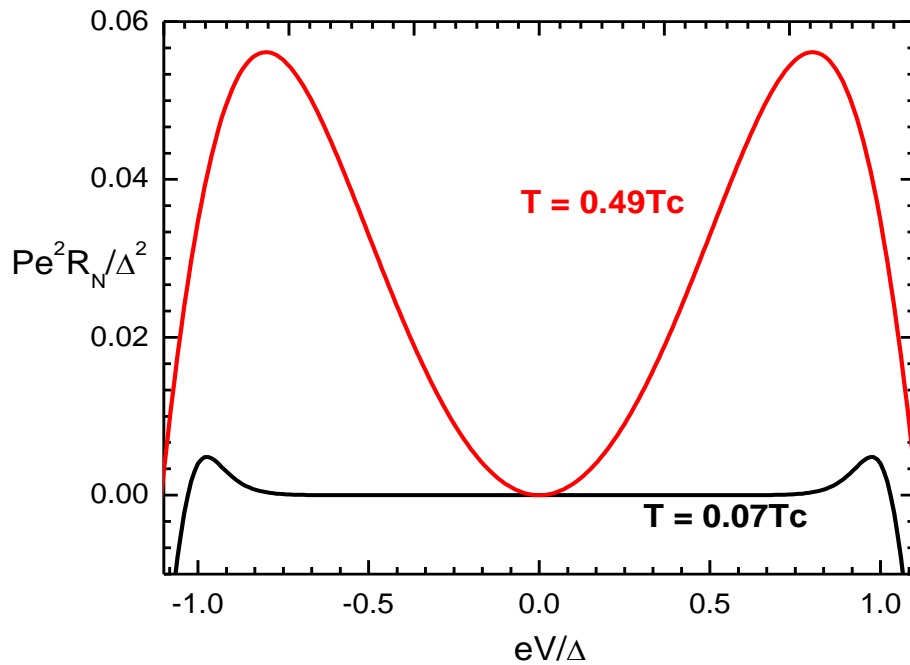
$$I_T = \frac{1}{eR_N} \int_{-\infty}^{\infty} n_S(E) [f_N(E - eV) - f_S(E)] dE$$



Voltage at fixed current measures **electronic** temperature

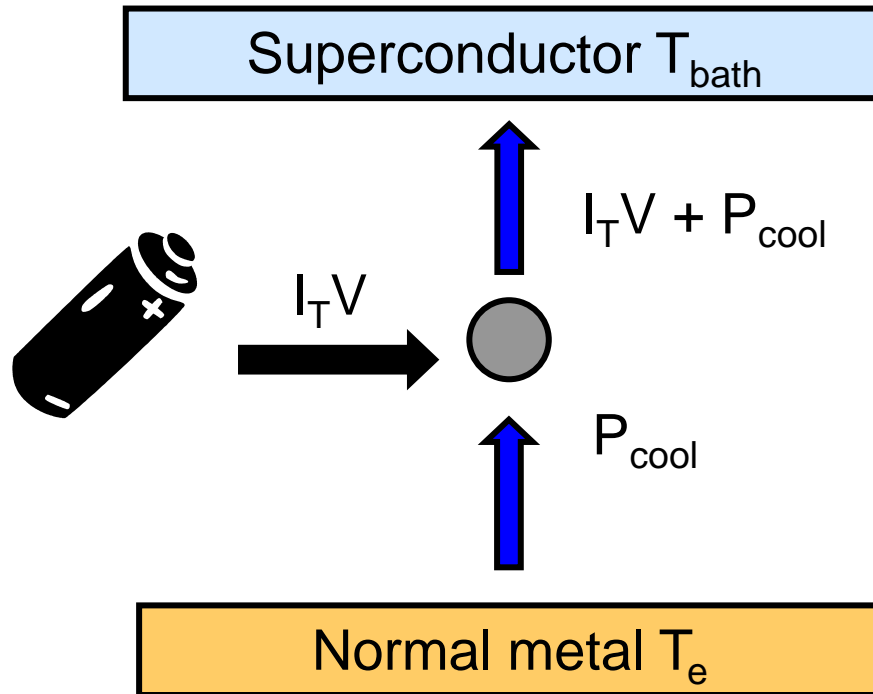
$T > 0 \text{ K}$

S-I-N-I-S electronic cooling



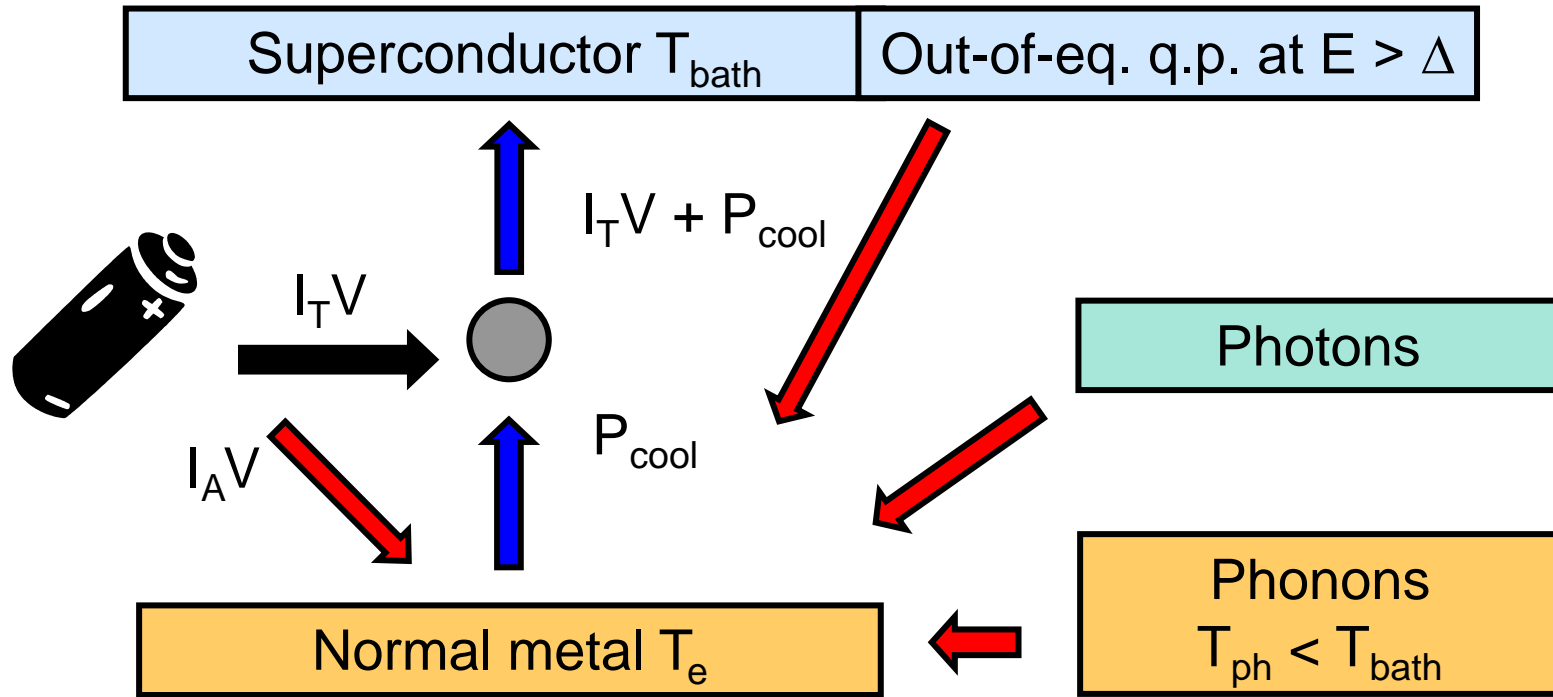
$$P_{cool} = \frac{1}{e^2 R_N} \int_{-\infty}^{\infty} (E - eV) n_S(E) [f_N(E - eV) - f_S(E)] dE$$

Limitations of electronic refrigeration



F. Giazotto, T. T. Heikkila, A. Luukanen, A. M. Savin and J. P. Pekola, Rev. Mod. Phys. 78, 217 (2006)

Limitations of electronic refrigeration



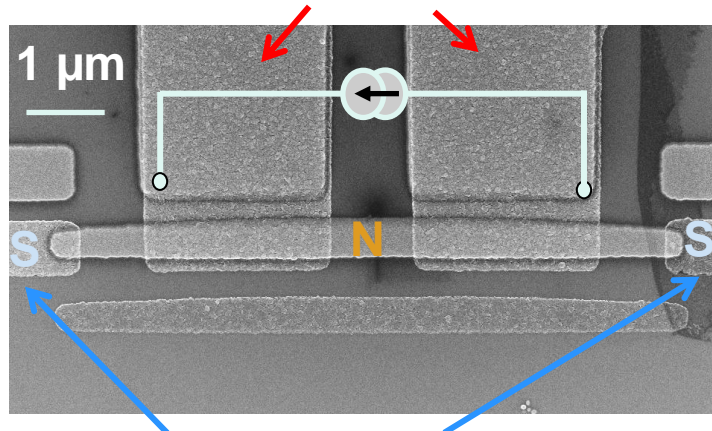
Our objective :

Understand the mechanisms coupling the cooled e- to the thermal baths.

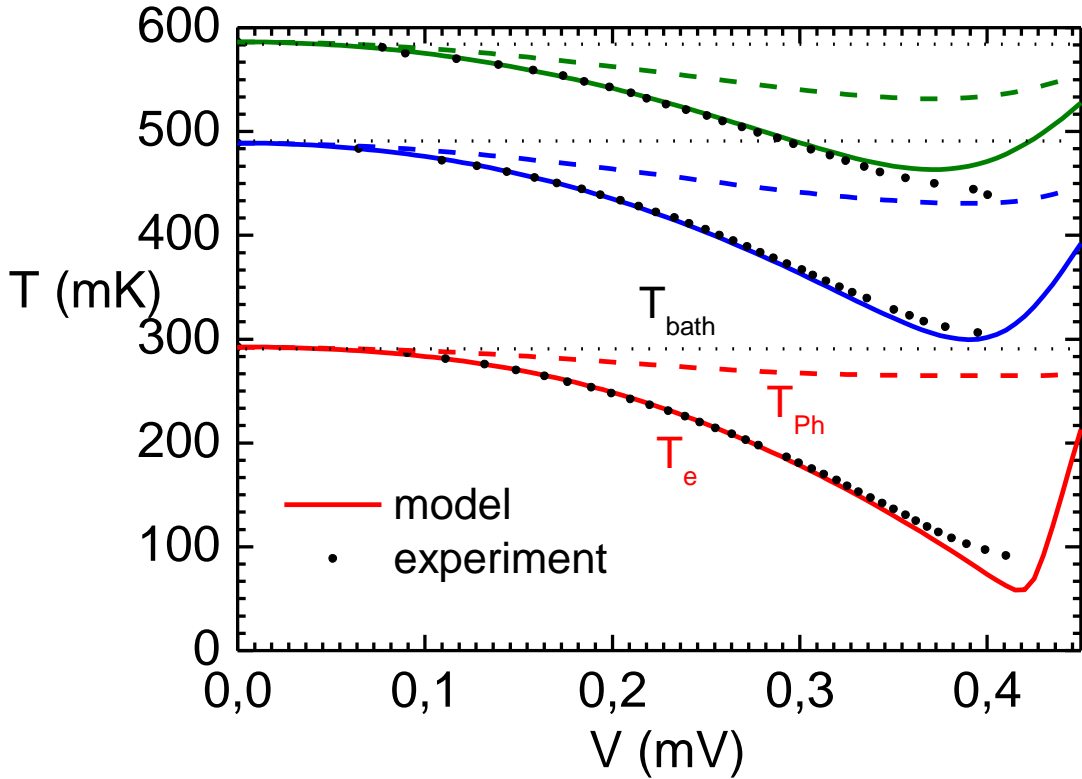
Performance of electronic refrigeration

Al/AlOx/Cu/AlOx/Al device:

Cooler junctions: N island weakly coupled to external world, strong cooling effect expected.



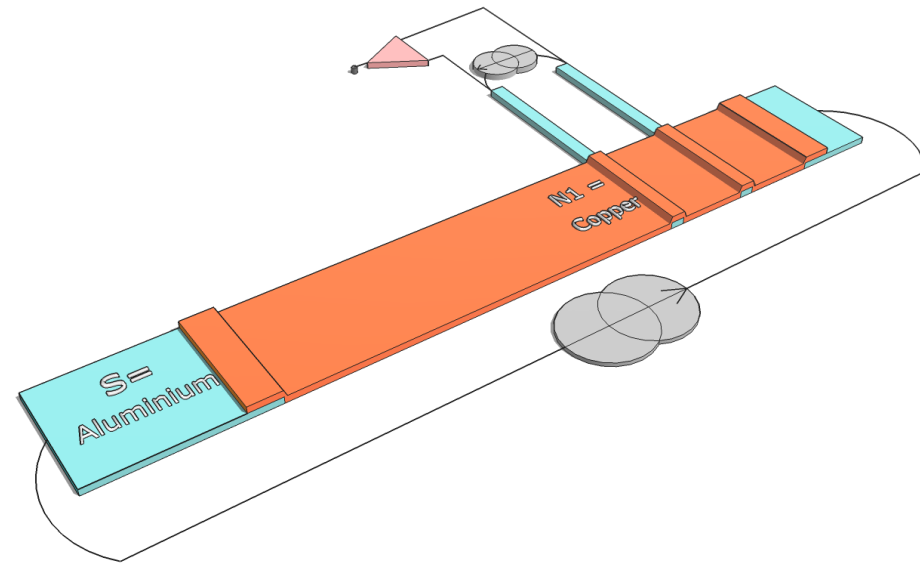
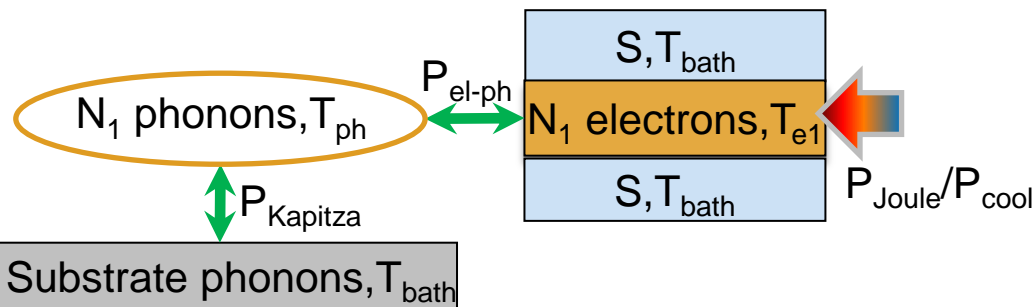
Thermometer junctions



Electrons cool from 0.3 down to < 0.1 K
 ~ 1.5 pW at 0.3 K, area junction $0.45 \mu m^2$
 S. Rajauria et al., PRL **99**, 047004 (2007)

Probing independently electron & phonon temperature...

Probe phonon temperature with S-I-N-I-S



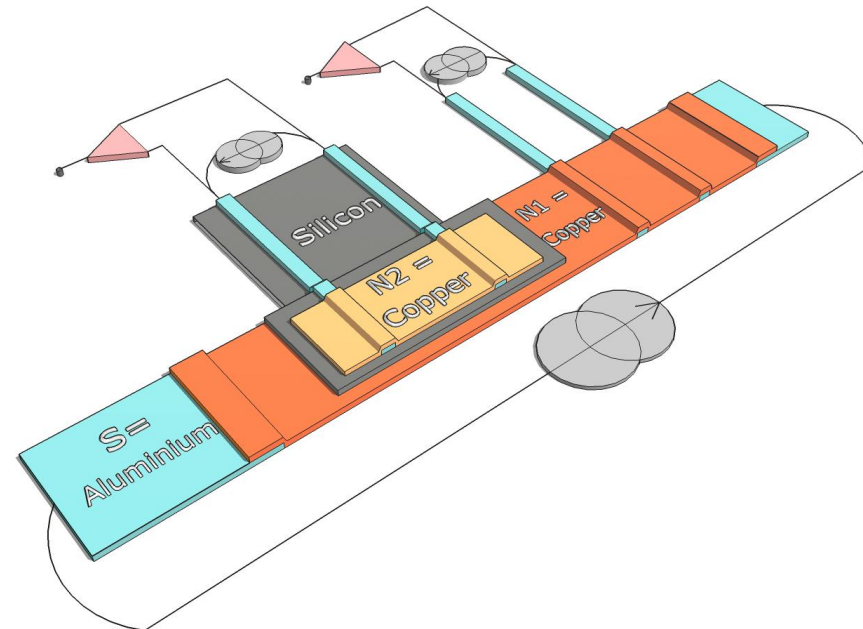
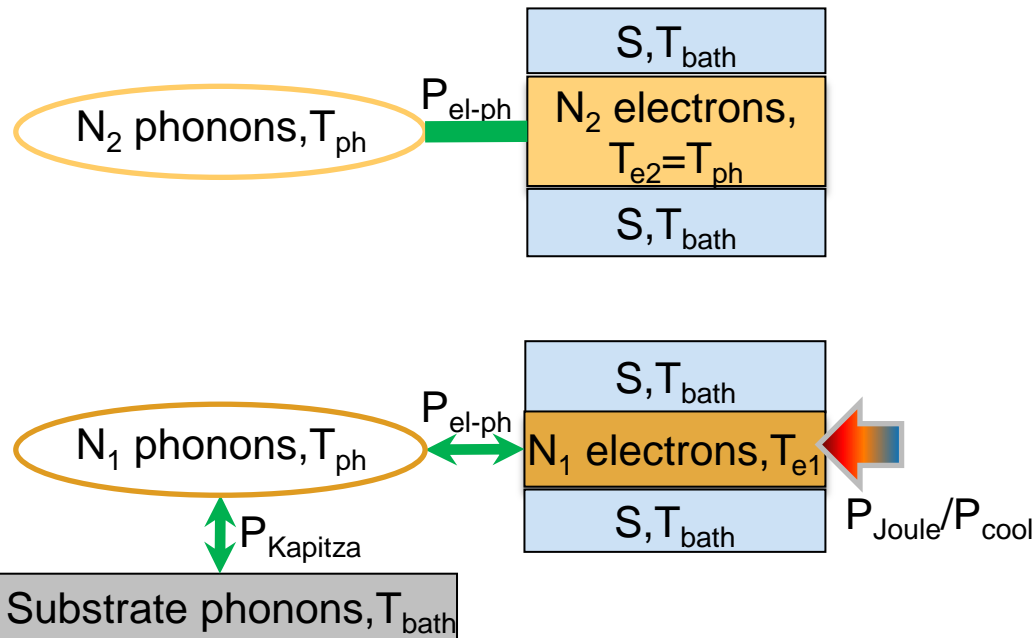
Theoretical expectations :

$$P_{el-ph} = \Sigma A d (T_e^5 - T_{ph}^5)$$

$$P_{Kapitza} = K A (T_{ph}^4 - T_{bath}^4)$$

Σ is material dependent prefactor,
K is the Kapitza coefficient,
A area, d thickness.

Probe phonon temperature with S-I-N-I-S



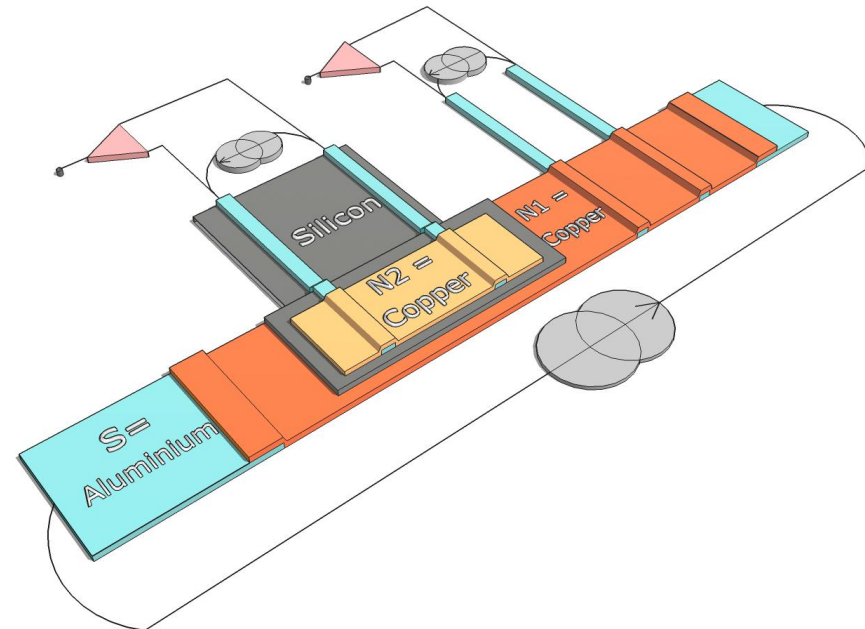
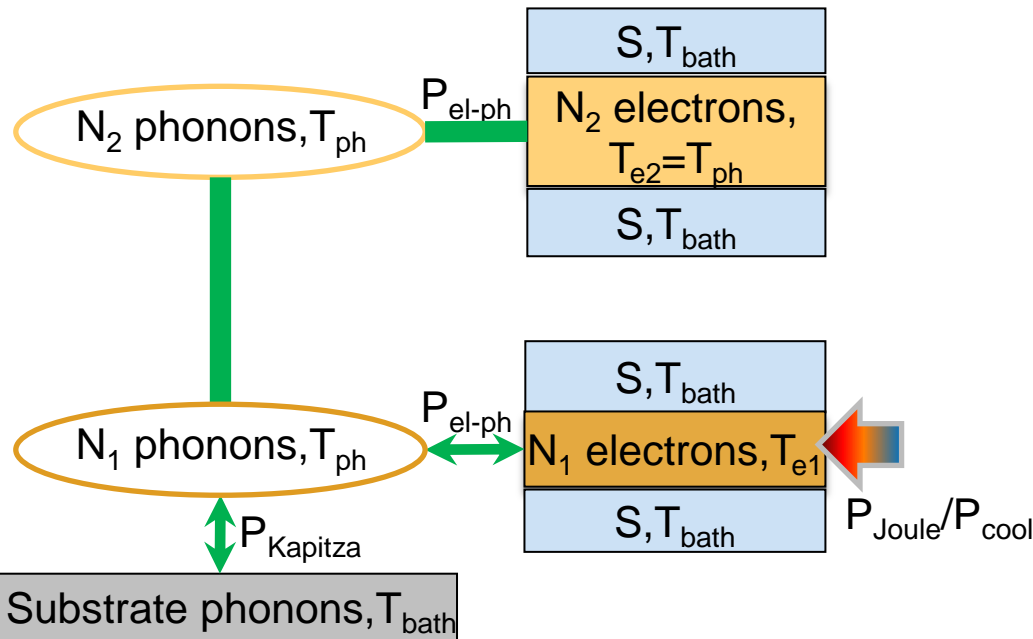
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Probe phonon temperature with S-I-N-I-S



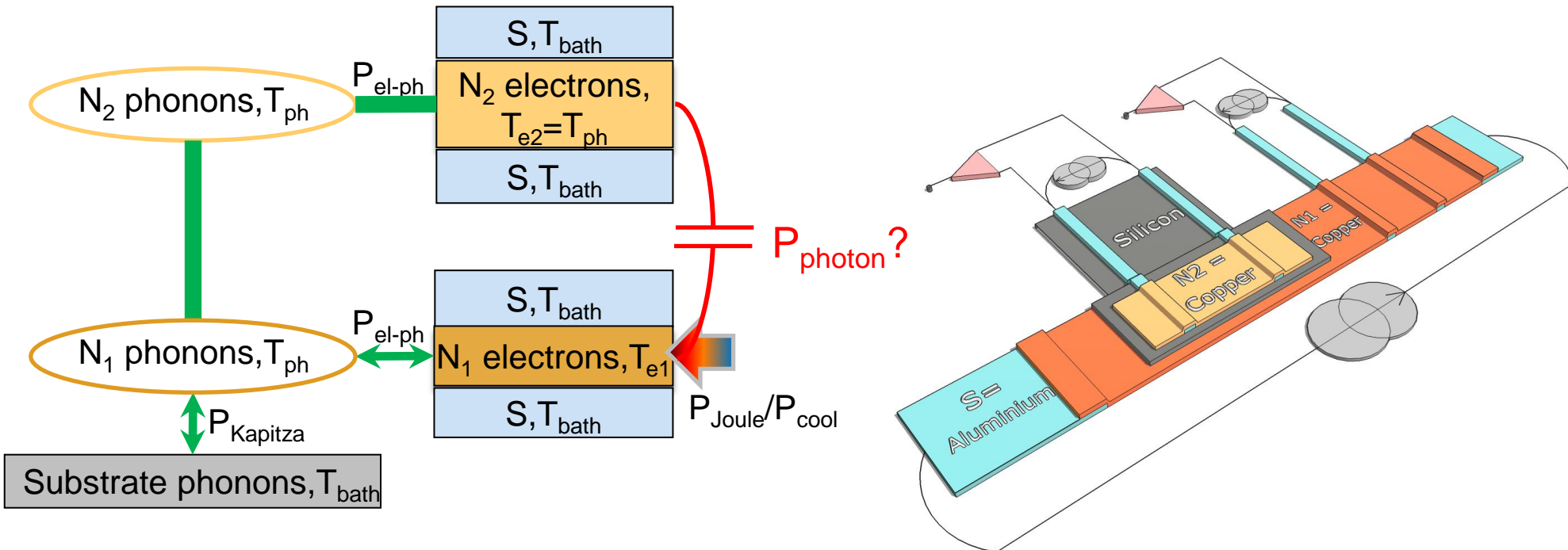
Theoretical expectations :

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 A area, d thickness.

Probe phonon temperature with S-I-N-I-S



Theoretical expectations :

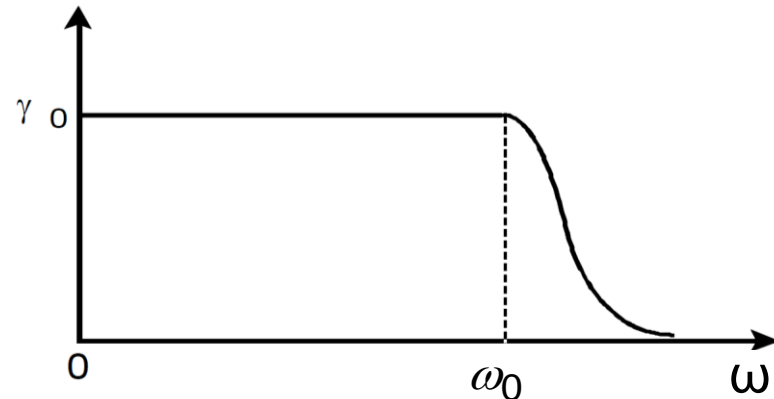
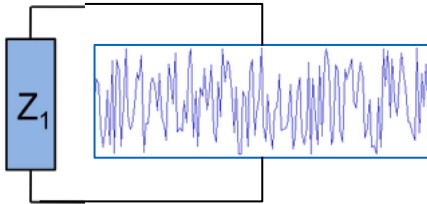
$$P_{el-ph} = \Sigma A d (T_e^5 - T_{ph}^5)$$

$$P_{Kapitza} = K A (T_{ph}^4 - T_{bath}^4)$$

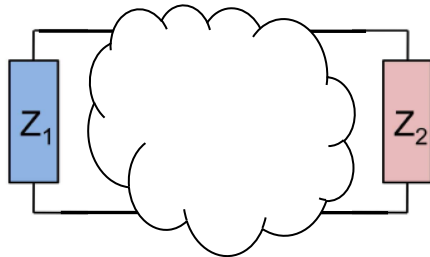
Σ is material dependent prefactor,
 K is the Kapitza coefficient,
 A area, d thickness.

Circuit approach to photonic heat transport

Thermal noise or Johnson-Nyquist noise



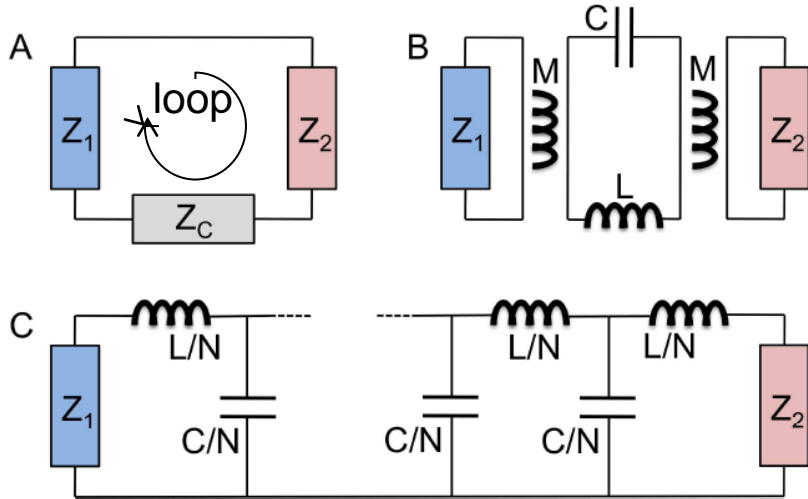
Noise is white below the thermal cut-off.



Photonic power from a hot resistor to a cold one coupled through an impedance?

D. Schmidt et al, Phys. Rev. Lett. **93**, 045901 (2004)

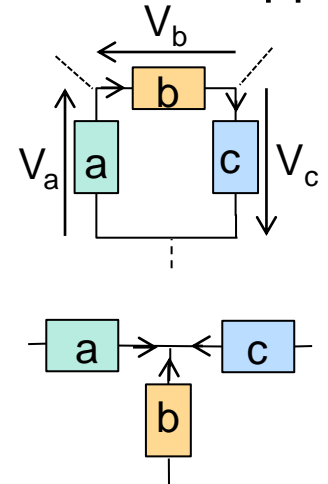
Circuit theory introduction



$L < \lambda_\omega$ (~ 1 cm at 1 K): Kirchoff's laws apply.

voltage: $\sum \Delta V_i = 0$

current: $\sum \Delta I_i = 0$



$$\Delta I_i = \delta I_i + \Delta V_i / Z_i$$

Fluctuation-dissipation theorem

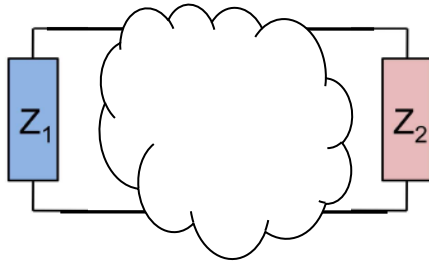
Current through Z_i

$$\langle \delta I_i(\omega) \delta I_i(\omega') \rangle = 2\pi \delta(\omega + \omega') \hbar \omega \Re \left[\frac{1}{Z_i(\omega)} \right] \left\{ 1 + 2 \frac{1}{e^{\hbar\omega/2k_B T} - 1} \right\} n_i(\omega)$$

Absorbed power:

$$P_i(t) = \langle \Delta I_i(t) \Delta V_i(t) \rangle = \int \frac{d\omega}{2\pi} \int \frac{d\omega'}{2\pi} e^{-i\omega t} e^{-i\omega' t} \langle \Delta I_i(\omega) \Delta V_i(\omega') \rangle$$

Absorbed power and linear inductance



Landauer-Büttiker – type formula: $P_1 = -P_2 = \int_0^{\infty} P(\omega) d\omega = \int_0^{\infty} \frac{d\omega}{2\pi} \hbar \omega T(\omega) [n_1(\omega) - n_2(\omega)]$

Photon transmission coefficient: $T(\omega) = \frac{4\Re[Z_1(\omega)]\Re[Z_2(\omega)]}{|Z_T(\omega)|^2}$

Linear heat conductance: $K = \frac{Tk_B^2}{\pi\hbar} \int_0^{\infty} dx T(x) \frac{x^2}{\sinh^2(x)}$ with $x = \frac{\hbar\omega}{2k_B T}$

Absorbed power and linear inductance



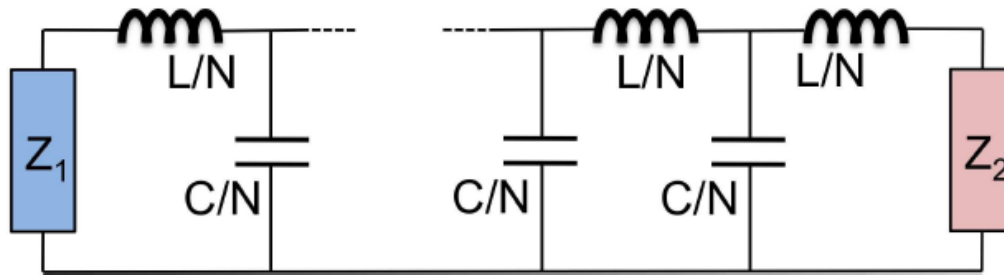
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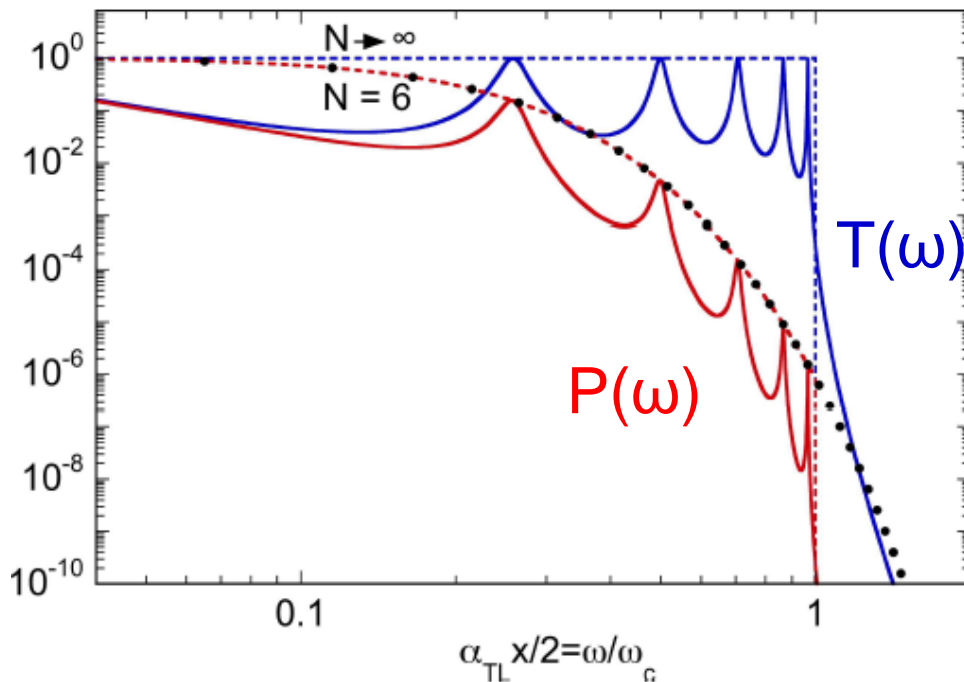
Linear heat conductance: $K = \frac{Tk_B^2}{\pi\hbar} \int_0^{\infty} dx T(x) \frac{x^2}{\sinh^2(x)}$ with $x = \frac{\hbar\omega}{2k_B T}$

If $T(\omega) = 1$, $K = K_Q = \frac{\pi^2 k_B^2 T}{3h}$ *thermal conductance quanta*, ~ 1 pW/K at 1 K,
see M. Meschke et al, Nature (2006).

Photonic heat transport in transmission line



Cut-off frequency $\omega_c = \frac{2}{\sqrt{LC}}$



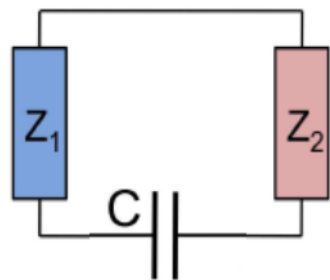
Total impedance Z_T :

$$\omega \ll \omega_c : Z_T(\omega) = (Z_1 + Z_2) \cos(N\alpha_{TL}) + i \sin(N\alpha_{TL}) \sqrt{\frac{L}{C}} \left[1 + Z_1 Z_2 \frac{C}{L} \right]$$

$$\omega \gg \omega_c : Z_T(\omega) = i\alpha_{TL} x \sqrt{\frac{L}{C}} [-x^2 \alpha_{TL}^2]^{N-1}$$

L. Pascal, H. Courtois, F. W. J. Hekking, Phys. Rev. B **83**, 125113 (2011)

Spectral density with a capacitive coupling



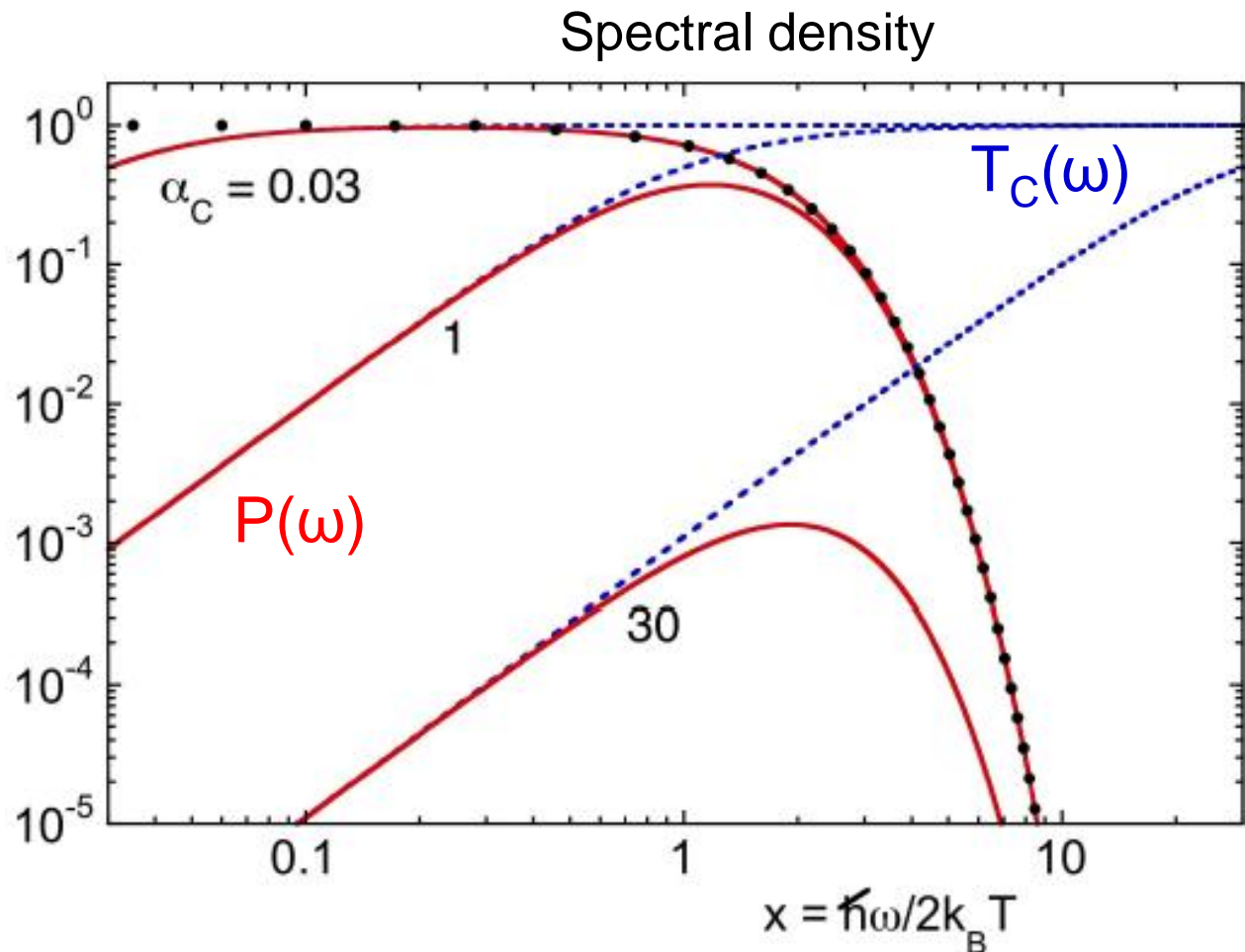
Transmission coefficient

$$T_C(\omega) = \frac{x^2}{\alpha_C^2 + x^2}$$

with

$$\alpha_C = \frac{\hbar}{4RCk_B T}$$

$$x = \frac{\hbar\omega}{2k_B T}$$



Spectral density with a capacitive coupling

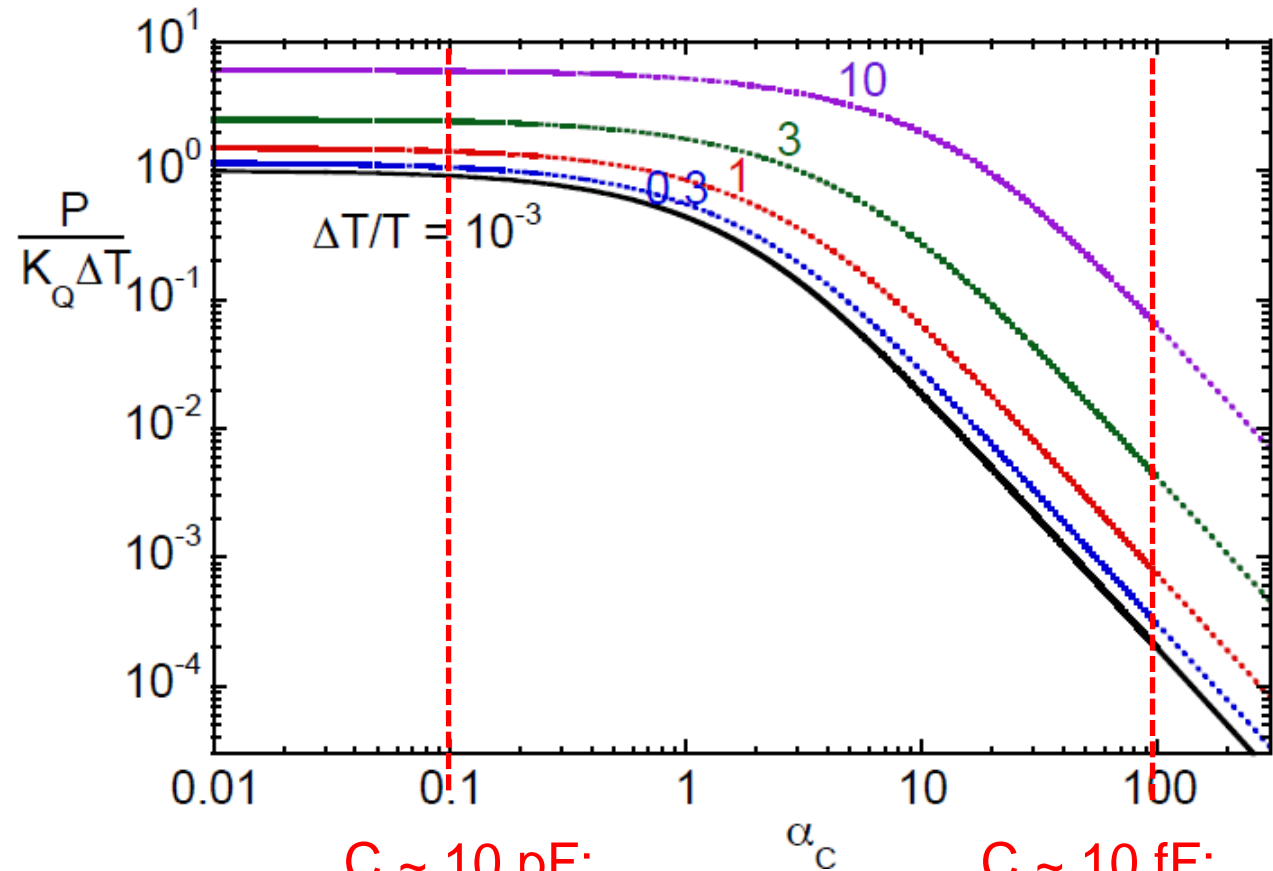
Typical parameters

$$R_1 = R_2 = R \sim 50 \Omega$$

$T \sim 40 \text{ mK}$

$K > K_Q$ for large ΔT .

$$\alpha_C = \frac{\hbar}{4RCk_B T}$$



$C \sim 10 \text{ pF}$:
strong coupling

$C \sim 10 \text{ fF}$:
small coupling

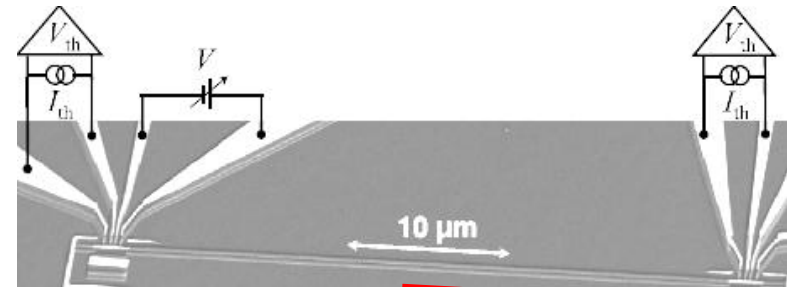
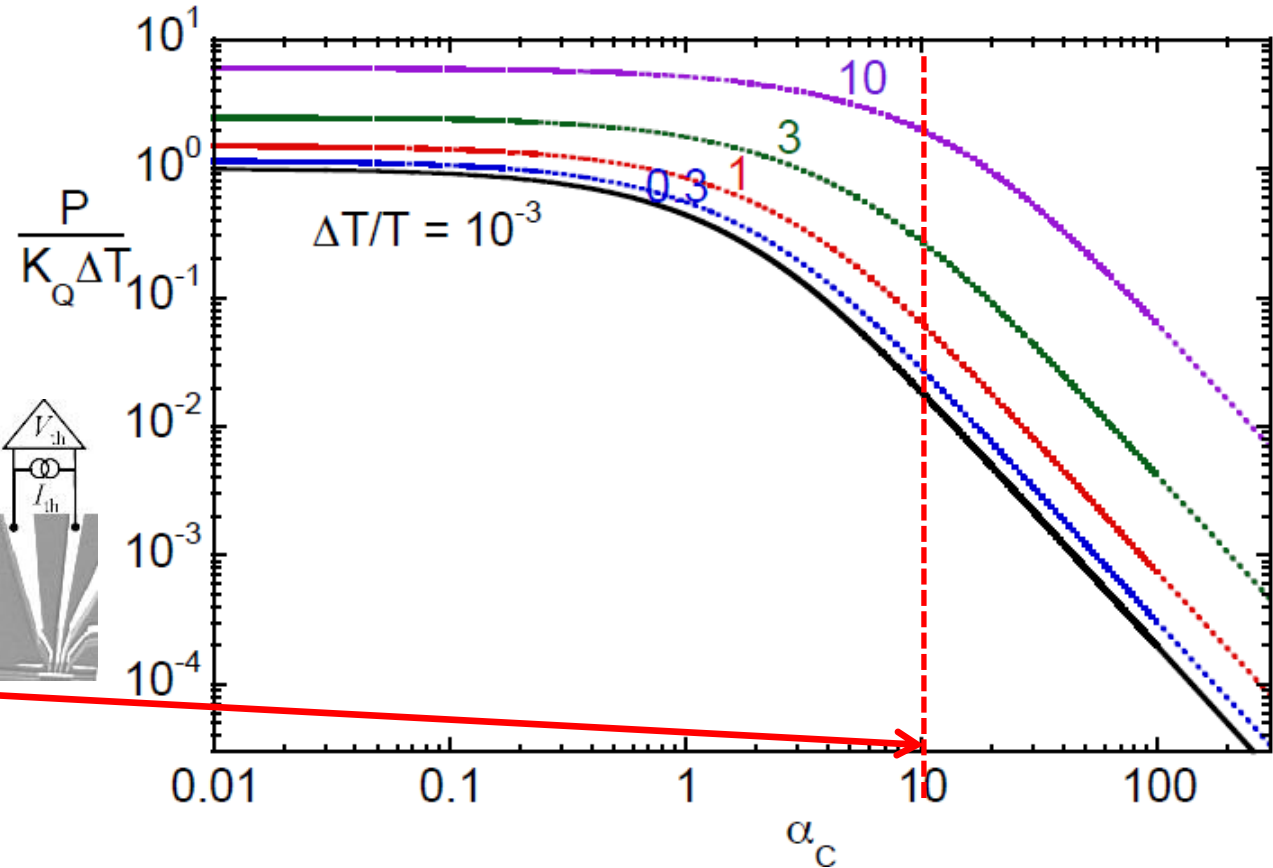
NEEL institut Spectral density with a capacitive coupling

Typical parameters

$$R_1 = R_2 = R \sim 230 \Omega$$

$T \sim 300$ down to 100 mK

$C \sim 10$ fF:



$$\alpha_C = \frac{\hbar}{4RCk_B T} < 10$$

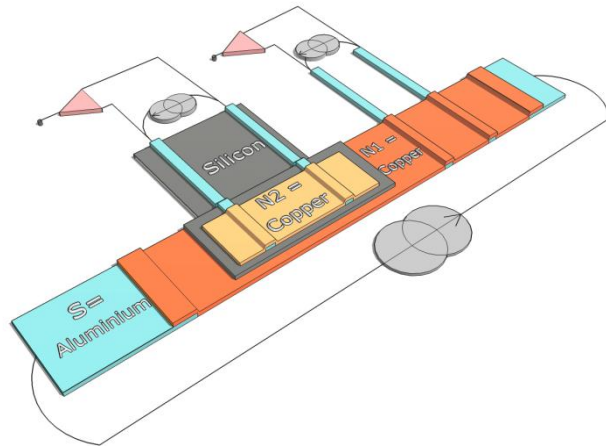
A. Timofeev et al., PRL **102**, 200801 (2009)

Spectral density with a capacitive coupling

Typical parameters

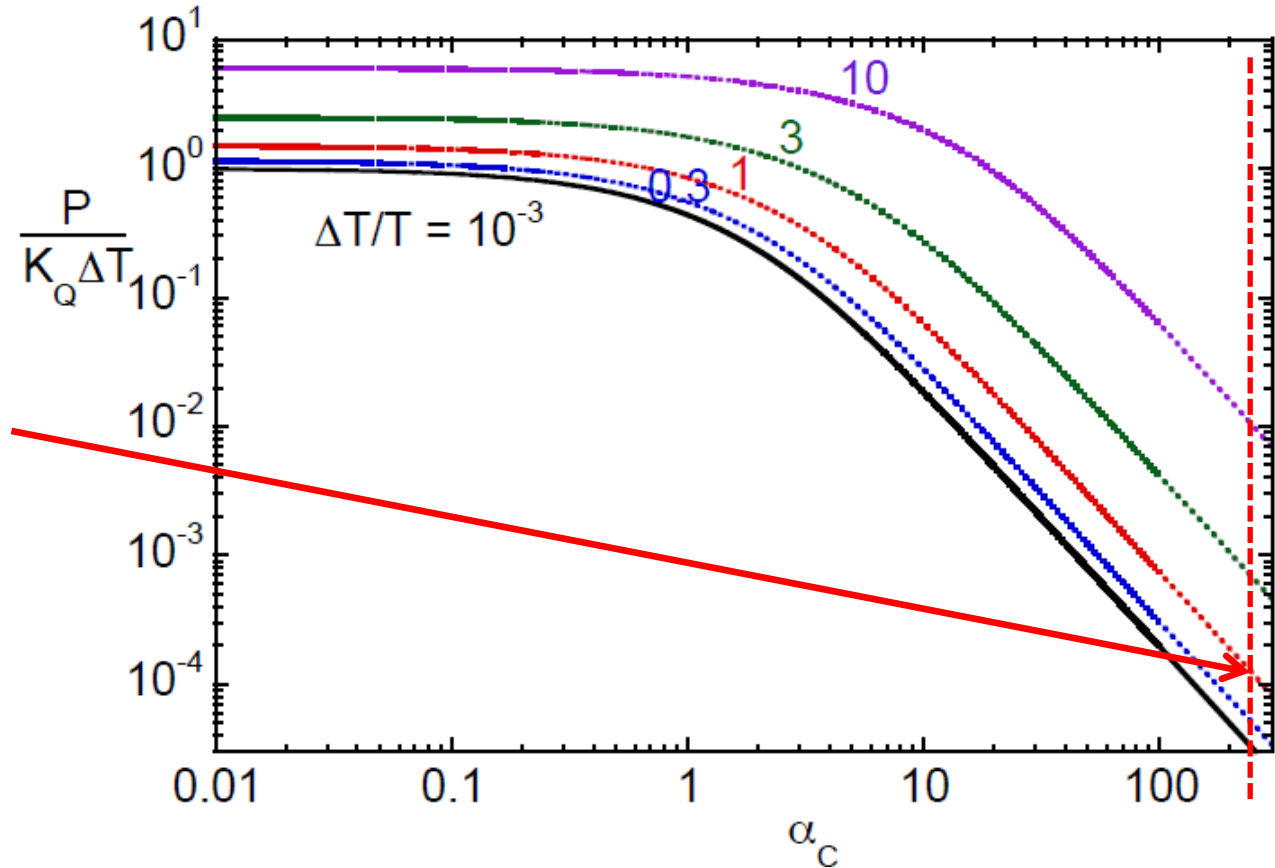
$$R_1 = R_2 = R \sim 50 \Omega$$

$$T \sim 300 \text{ mK}$$



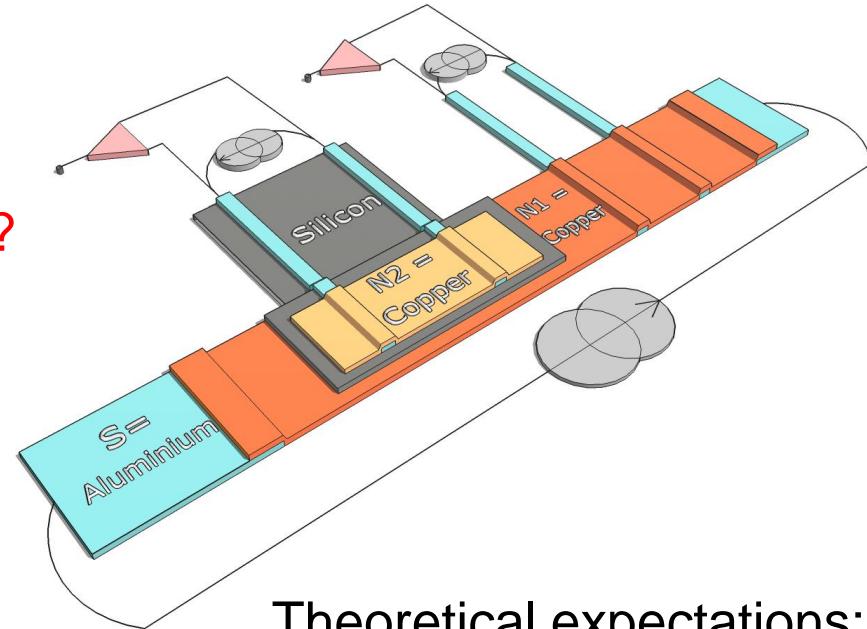
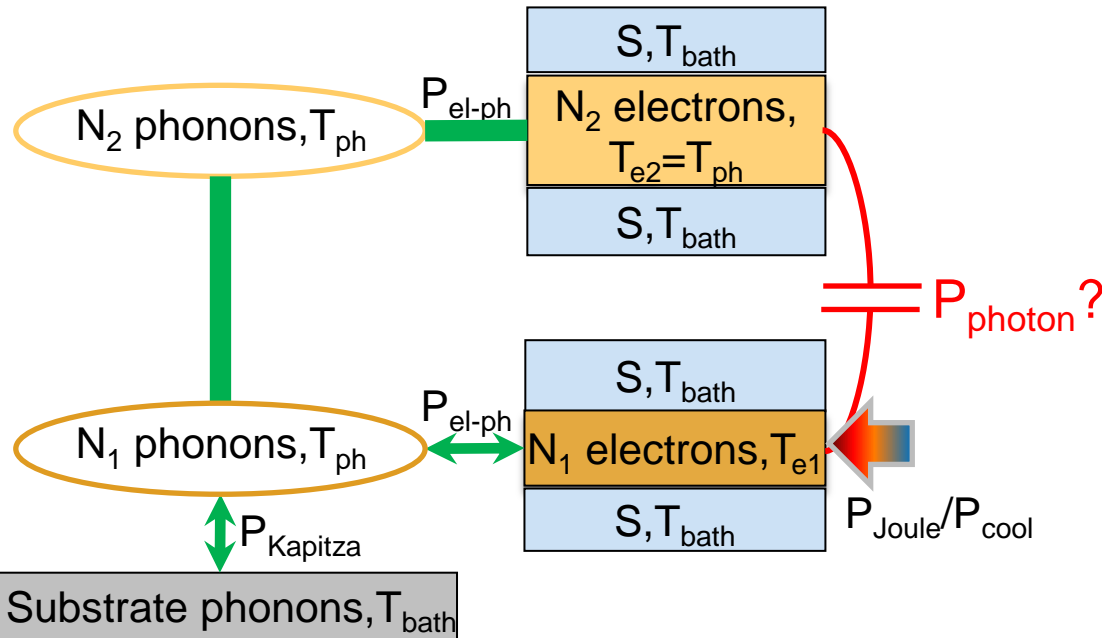
Our work:

$$\alpha_{\text{cexp.}} = \frac{\hbar}{4RCk_B T} \gg 10$$



...back to probing independently
electron & phonon temperature...

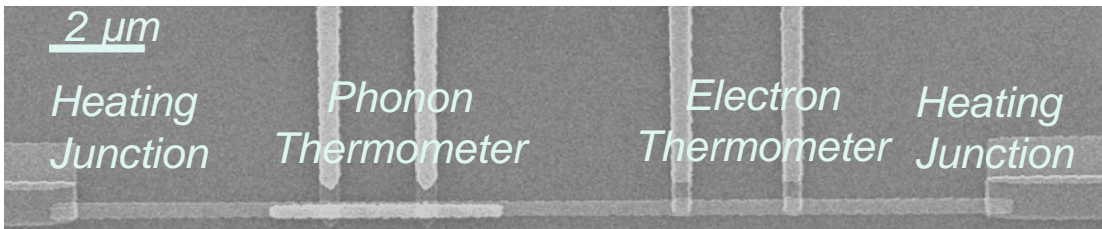
Probing phonon temperature



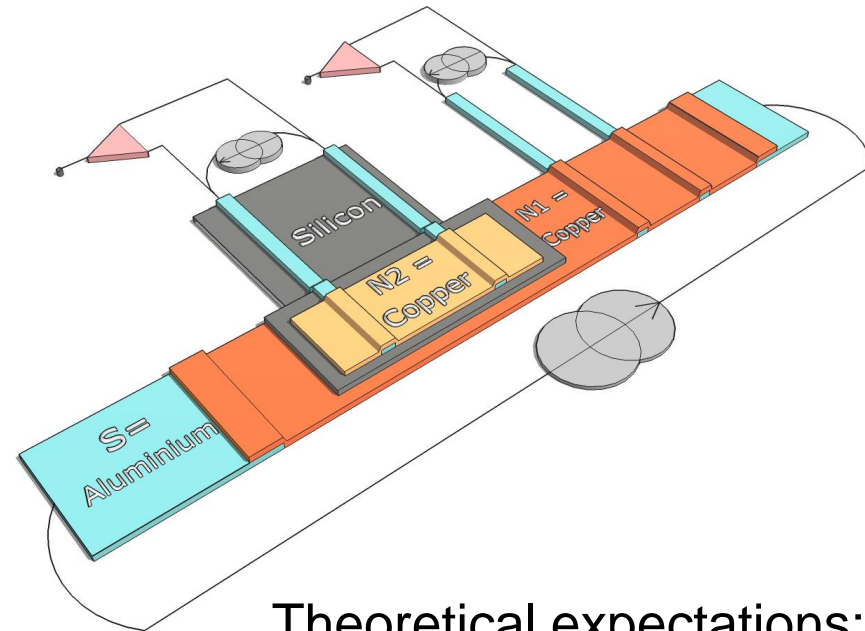
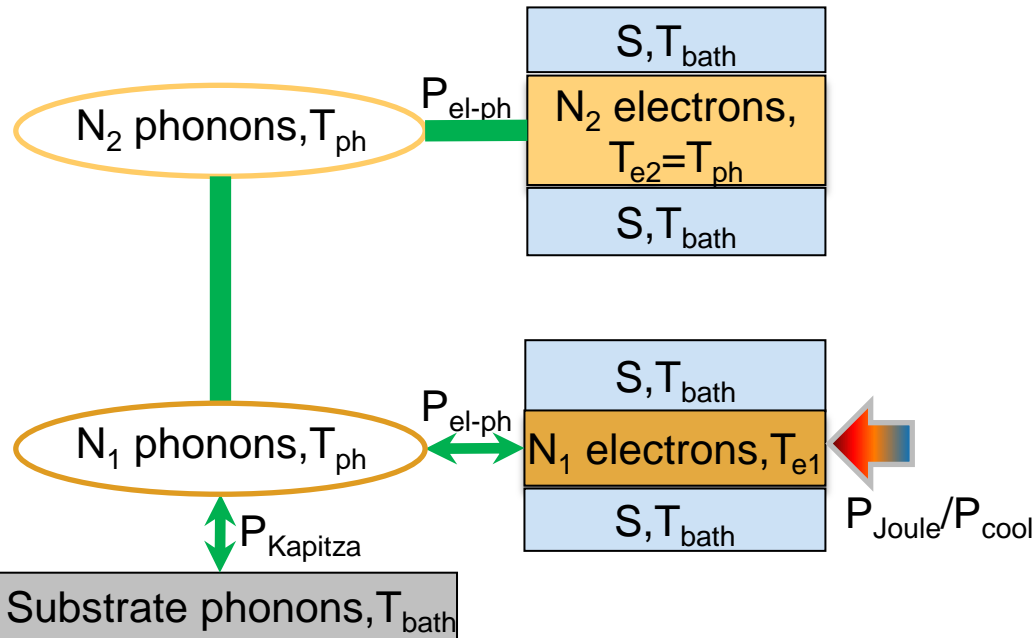
Theoretical expectations:

$$P_{el-ph} = \Sigma A d (T_e^5 - T_{ph}^5)$$

$$P_{Kapitza} = KA (T_{ph}^4 - T_{bath}^4)$$



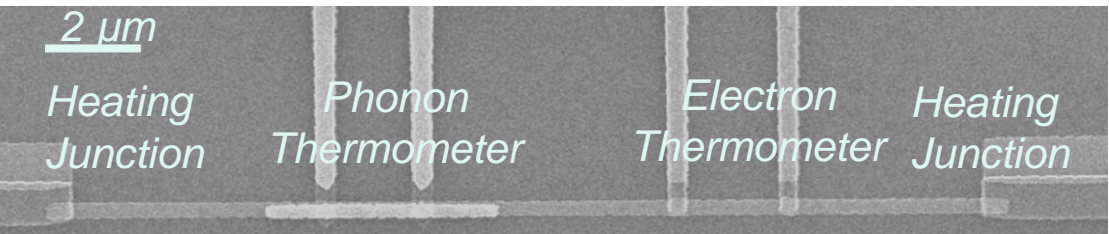
Probing phonon temperature



Theoretical expectations:

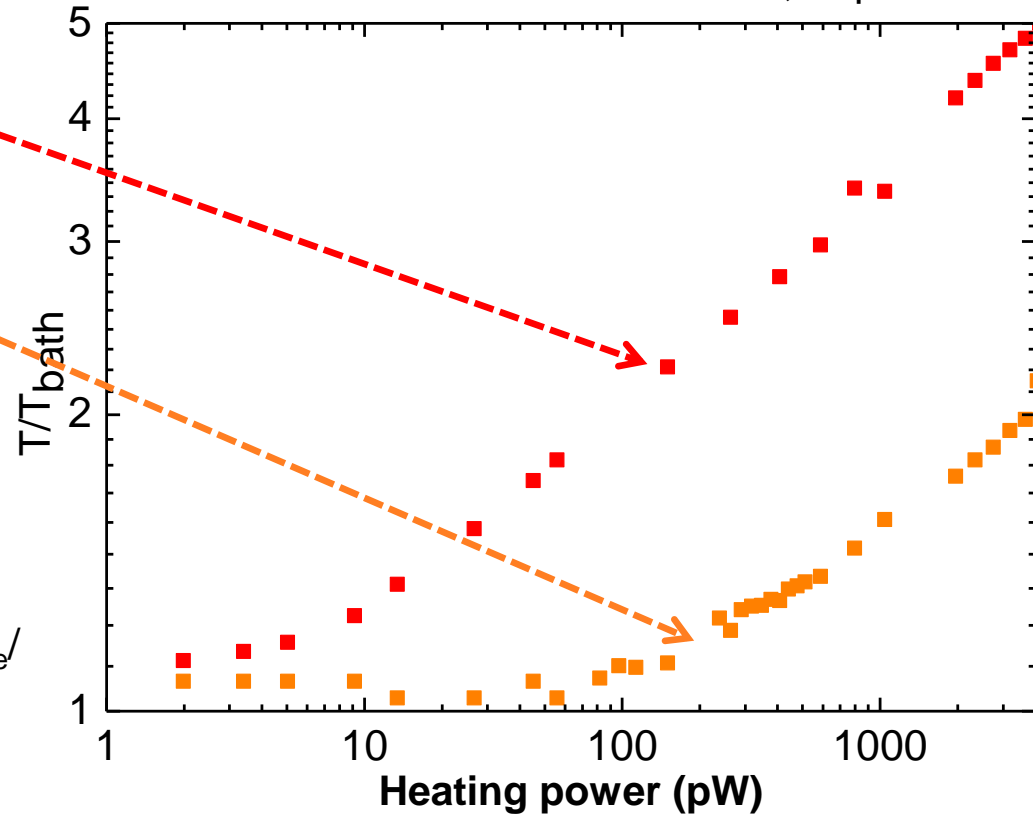
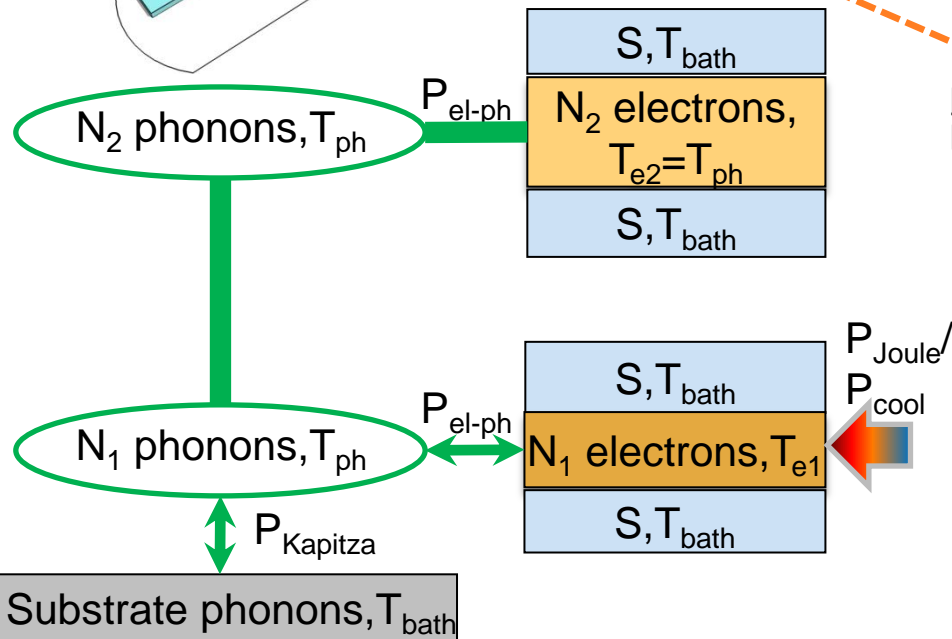
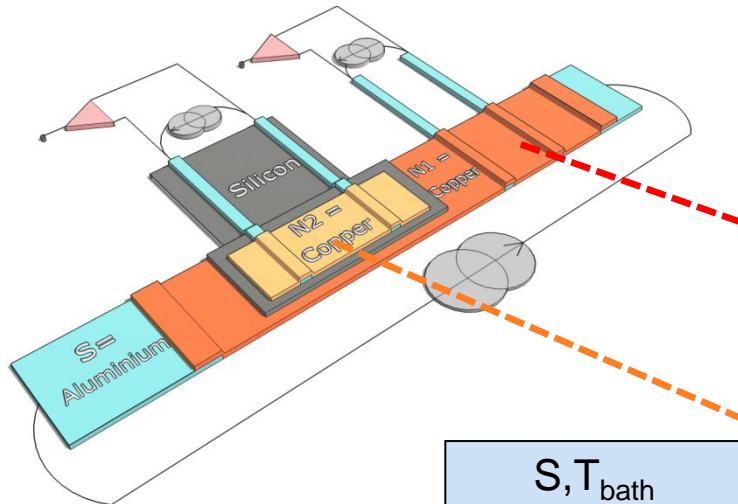
$$P_{el-ph} = \Sigma Ad(T_e^5 - T_{ph}^5)$$

$$P_{Kapitza} = KA(T_{ph}^4 - T_{bath}^4)$$

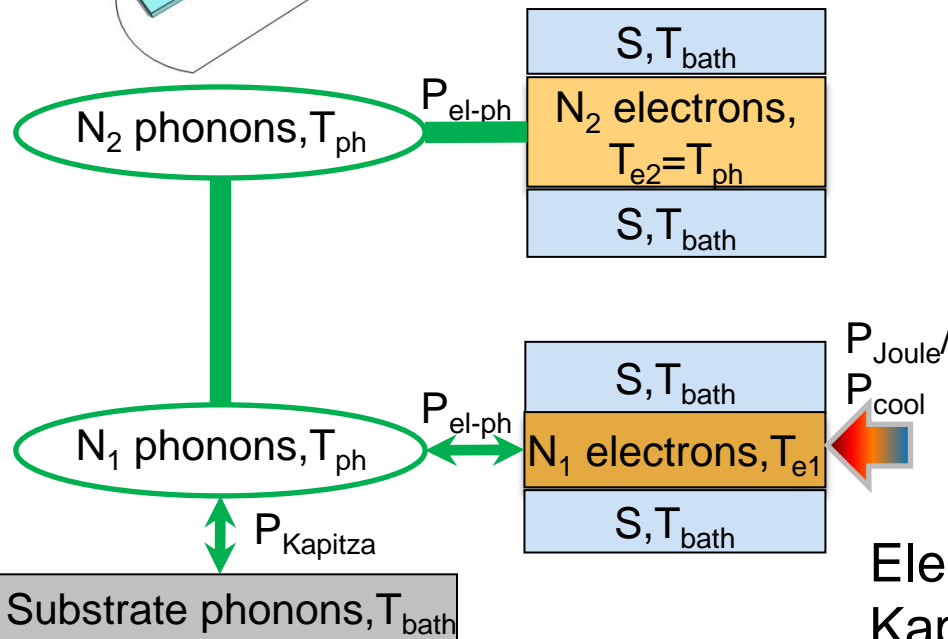
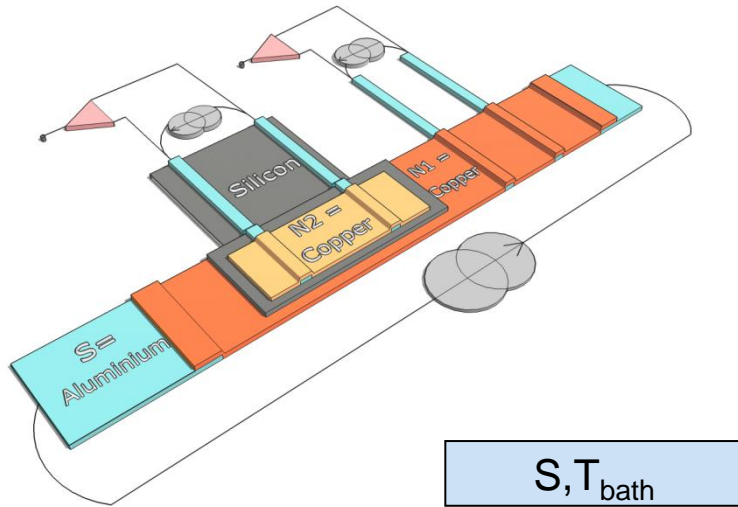


Probing phonon temperature

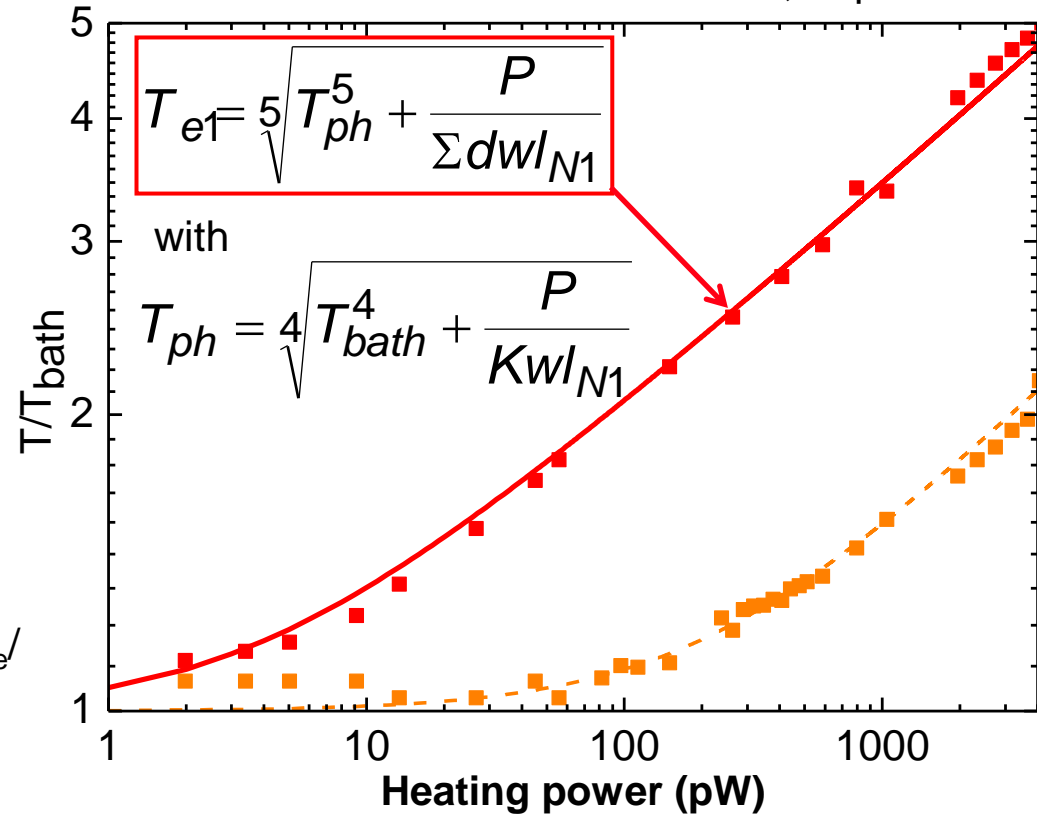
L. Pascal et al., unpublished



Probing phonon temperature

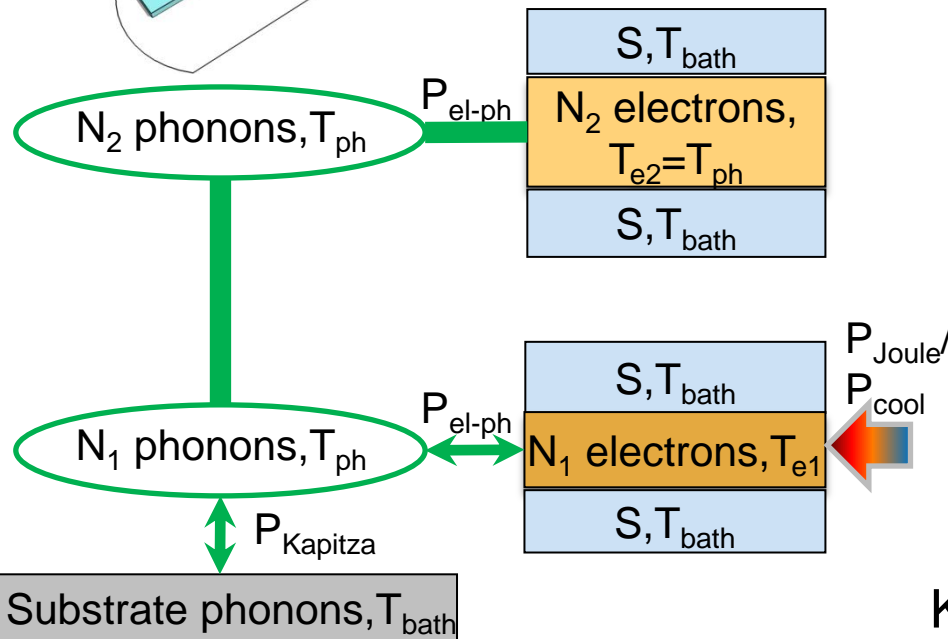
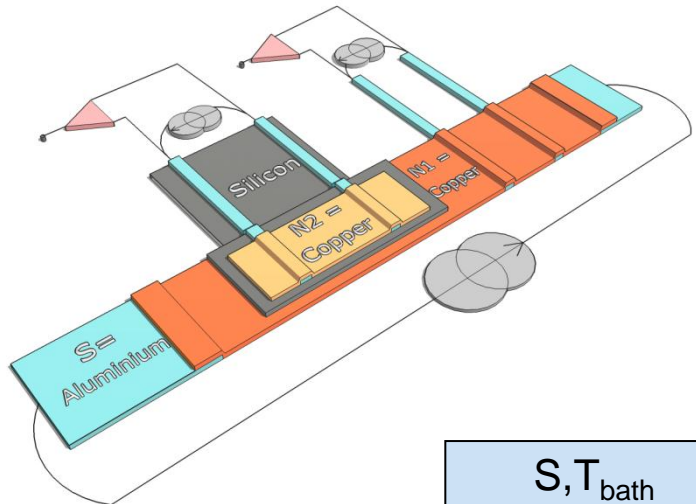


L. Pascal et al., unpublished

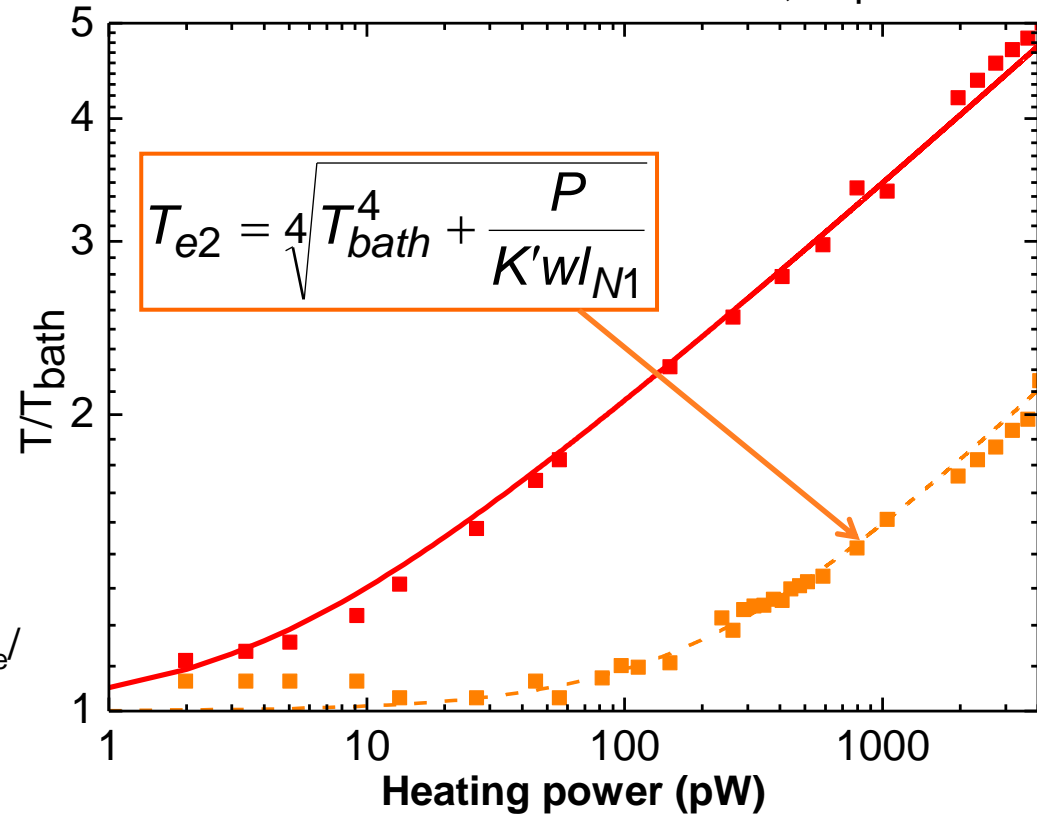


Electron-phonon coupling : $\Sigma = 2 \cdot 10^9 \text{ W.m}^{-3} \cdot \text{K}^{-5}$
 Kapitza coupling: $K = 7 \cdot 10^7 \text{ W.m}^{-2} \cdot \text{K}^{-4}$

Probing phonon temperature

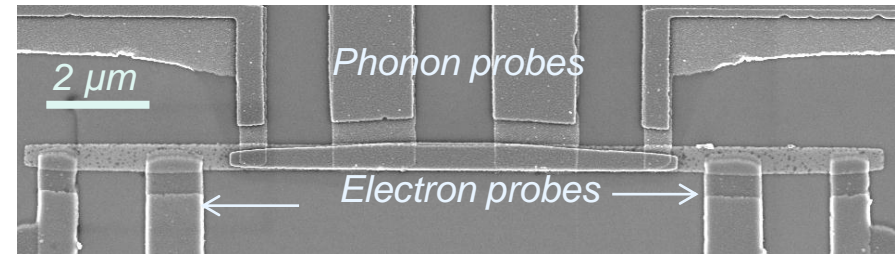
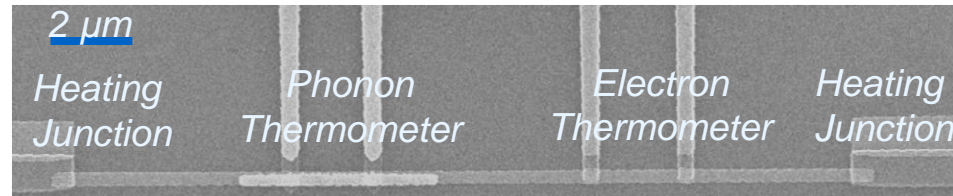
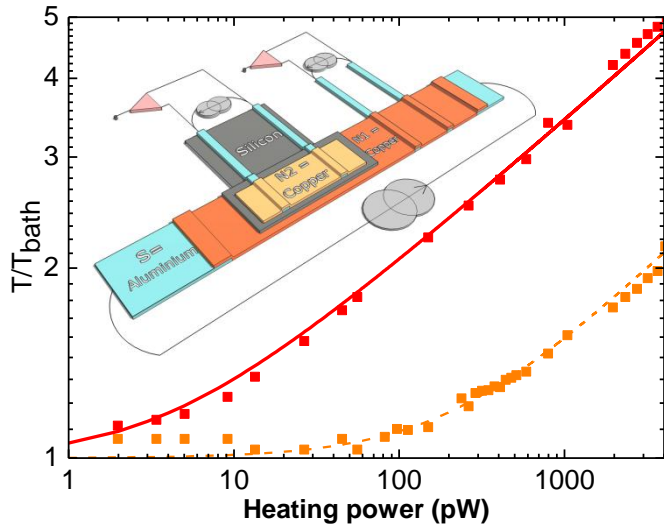
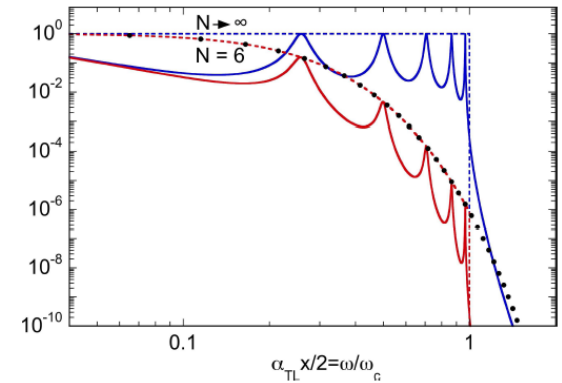
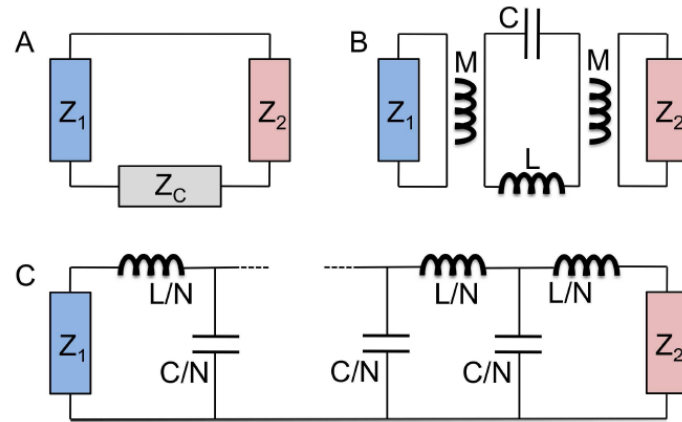
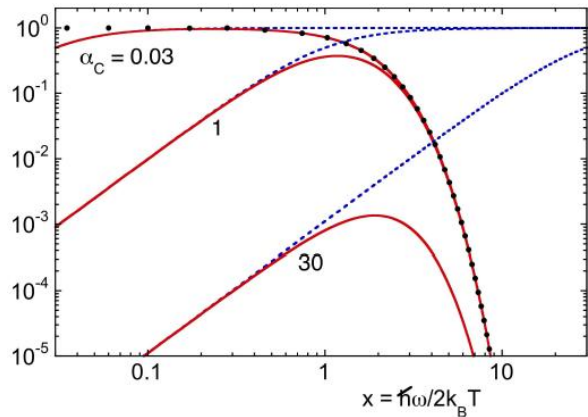


L. Pascal et al., unpublished



Kapitza coupling : $K' = 7 \cdot 10^8 \text{ W.m}^{-2} \cdot \text{K}^{-4}$

Conclusion & Perspectives



Thanks for your attention !